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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	12
Program Memory Size	1.5KB (1K x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	25 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SSOP (0.209", 5.30mm Width)
Supplier Device Package	20-SSOP
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/pic16c56a-04-ss">https://www.e-xfl.com/product-detail/microchip-technology/pic16c56a-04-ss</a>

# PIC16C5X

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NOTES:

# PIC16C5X

**TABLE 3-2: PINOUT DESCRIPTION - PIC16C55, PIC16C57, PIC16CR57**

Pin Name	Pin Number			Pin Type	Buffer Type	Description
	DIP	SOIC	SSOP			
RA0	6	6	5	I/O	TTL	Bi-directional I/O port
RA1	7	7	6	I/O	TTL	
RA2	8	8	7	I/O	TTL	
RA3	9	9	8	I/O	TTL	
RB0	10	10	9	I/O	TTL	Bi-directional I/O port
RB1	11	11	10	I/O	TTL	
RB2	12	12	11	I/O	TTL	
RB3	13	13	12	I/O	TTL	
RB4	14	14	13	I/O	TTL	
RB5	15	15	15	I/O	TTL	
RB6	16	16	16	I/O	TTL	
RB7	17	17	17	I/O	TTL	
RC0	18	18	18	I/O	TTL	Bi-directional I/O port
RC1	19	19	19	I/O	TTL	
RC2	20	20	20	I/O	TTL	
RC3	21	21	21	I/O	TTL	
RC4	22	22	22	I/O	TTL	
RC5	23	23	23	I/O	TTL	
RC6	24	24	24	I/O	TTL	
RC7	25	25	25	I/O	TTL	
T0CKI	1	1	2	I	ST	Clock input to Timer0. Must be tied to Vss or VDD, if not in use, to reduce current consumption.
$\overline{\text{MCLR}}$	28	28	28	I	ST	Master clear (RESET) input. This pin is an active low RESET to the device.
OSC1/CLKIN	27	27	27	I	ST	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	26	26	26	O	—	Oscillator crystal output. Connects to crystal or resonator in crystal Oscillator mode. In RC mode, OSC2 pin outputs CLKOUT which has 1/4 the frequency of OSC1, and denotes the instruction cycle rate.
VDD	2	2	3,4	P	—	Positive supply for logic and I/O pins.
Vss	4	4	1,14	P	—	Ground reference for logic and I/O pins.
N/C	3,5	3,5	—	—	—	Unused, do not connect.

Legend: I = input, O = output, I/O = input/output, P = power, — = Not Used, TTL = TTL input, ST = Schmitt Trigger input

# PIC16C5X

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NOTES:

# PIC16C5X

FIGURE 5-3: TIME-OUT SEQUENCE ON POWER-UP ( $\overline{\text{MCLR}}$  NOT TIED TO VDD)

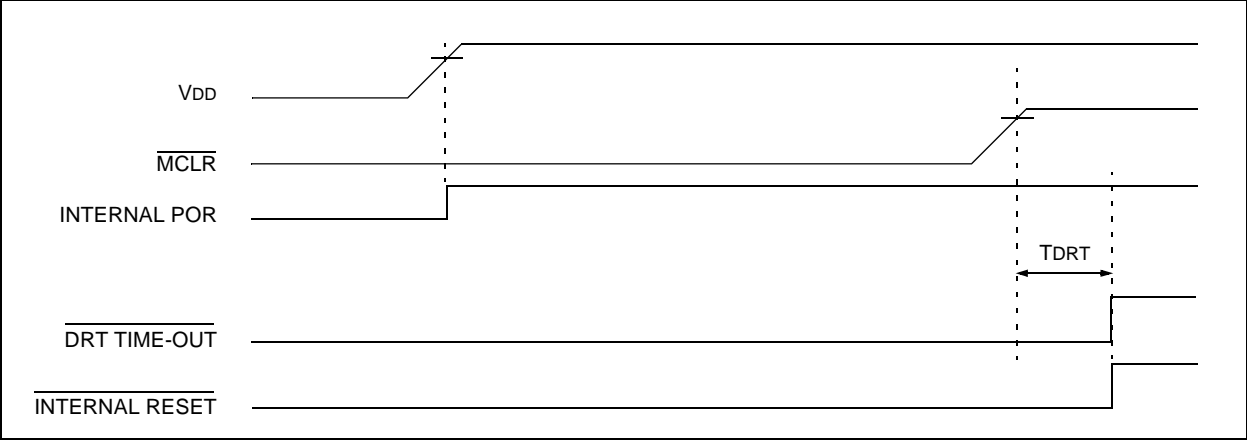


FIGURE 5-4: TIME-OUT SEQUENCE ON POWER-UP ( $\overline{\text{MCLR}}$  TIED TO VDD): FAST VDD RISE TIME

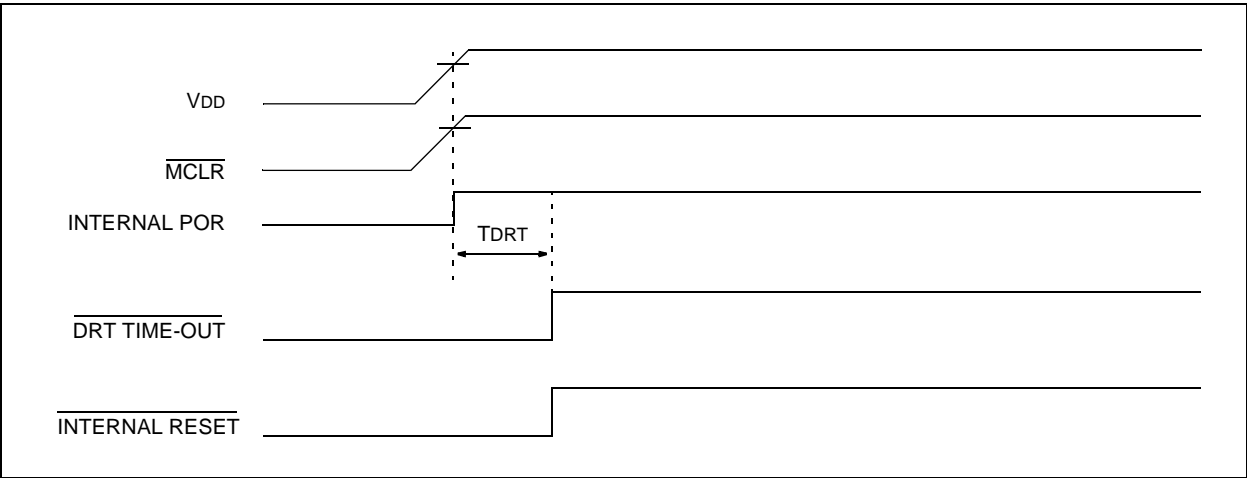
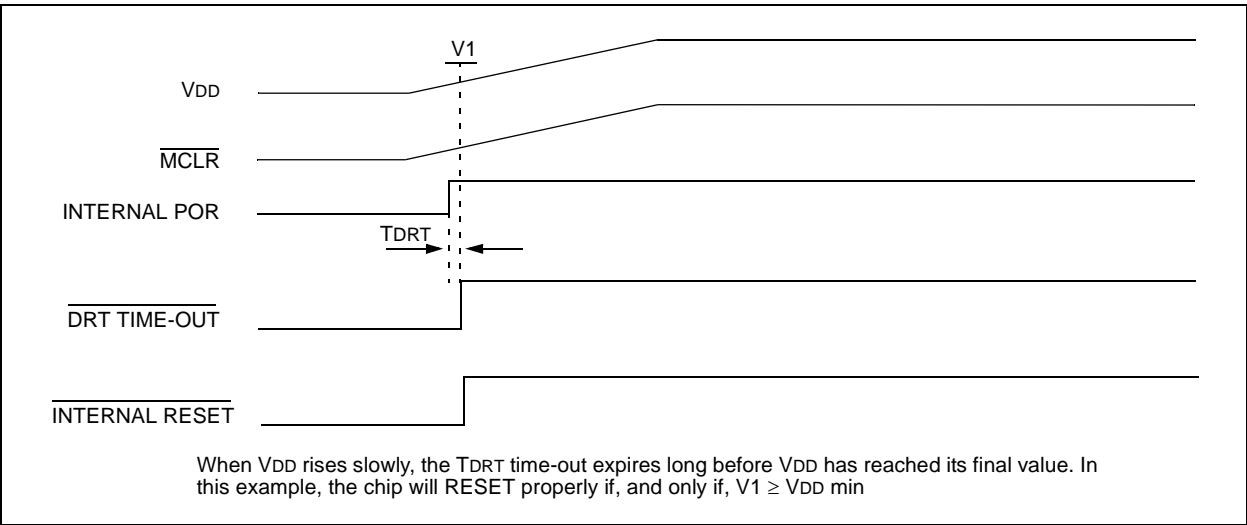


FIGURE 5-5: TIME-OUT SEQUENCE ON POWER-UP ( $\overline{\text{MCLR}}$  TIED TO VDD): SLOW VDD RISE TIME



# PIC16C5X

## 6.2 Data Memory Organization

Data memory is composed of registers, or bytes of RAM. Therefore, data memory for a device is specified by its register file. The register file is divided into two functional groups: Special Function Registers and General Purpose Registers.

The Special Function Registers include the TMR0 register, the Program Counter (PC), the Status Register, the I/O registers (ports) and the File Select Register (FSR). In addition, Special Purpose Registers are used to control the I/O port configuration and prescaler options.

The General Purpose Registers are used for data and control information under command of the instructions.

For the PIC16C54, PIC16CR54, PIC16C56 and PIC16CR56, the register file is composed of 7 Special Function Registers and 25 General Purpose Registers (Figure 6-4).

For the PIC16C55, the register file is composed of 8 Special Function Registers and 24 General Purpose Registers.

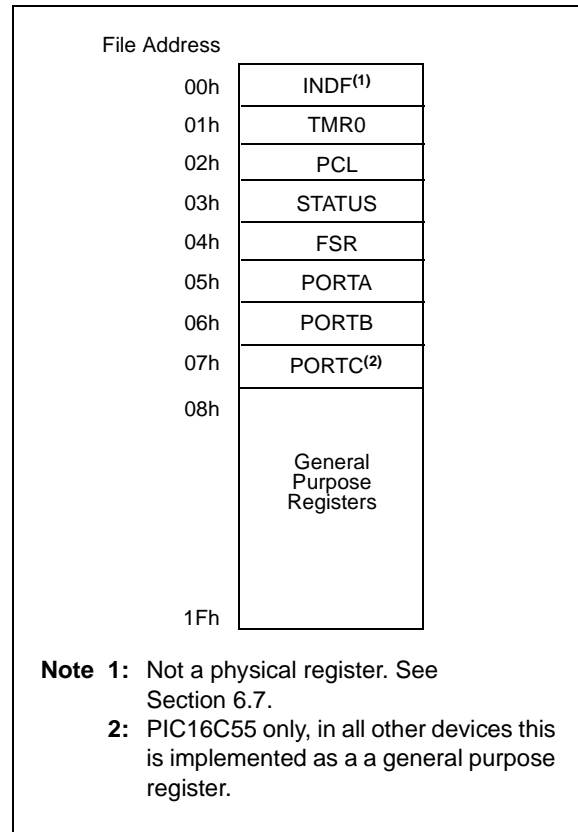
For the PIC16C57 and PIC16CR57, the register file is composed of 8 Special Function Registers, 24 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-5).

For the PIC16C58 and PIC16CR58, the register file is composed of 7 Special Function Registers, 25 General Purpose Registers and up to 48 additional General Purpose Registers that may be addressed using a banking scheme (Figure 6-6).

### 6.2.1 GENERAL PURPOSE REGISTER FILE

The register file is accessed either directly or indirectly through the File Select Register (FSR). The FSR Register is described in Section 6.7.

**FIGURE 6-4: PIC16C54, PIC16CR54, PIC16C55, PIC16C56, PIC16CR56 REGISTER FILE MAP**



# PIC16C5X

## 12.3 DC Characteristics: PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)

PIC16C54/55/56/57-RCE, XTE, 10E, HSE, LPE (Extended)			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ for extended				
Param No.	Symbol	Characteristic/Device	Min	Typ†	Max	Units	Conditions
D001	VDD	<b>Supply Voltage</b>					
		PIC16C5X-RCE	3.25	—	6.0	V	
		PIC16C5X-XTE	3.25	—	6.0	V	
		PIC16C5X-10E	4.5	—	5.5	V	
		PIC16C5X-HSE	4.5	—	5.5	V	
		PIC16C5X-LPE	2.5	—	6.0	V	
D002	VDR	<b>RAM Data Retention Voltage</b> <sup>(1)</sup>	—	1.5*	—	V	Device in SLEEP mode
D003	VPOR	<b>VDD Start Voltage</b> to ensure Power-on Reset	—	VSS	—	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	<b>VDD Rise Rate</b> to ensure Power-on Reset	0.05*	—	—	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	<b>Supply Current</b> <sup>(2)</sup>					
		PIC16C5X-RCE <sup>(3)</sup>	—	1.8	3.3	mA	FOSC = 4 MHz, VDD = 5.5V
		PIC16C5X-XTE	—	1.8	3.3	mA	FOSC = 4 MHz, VDD = 5.5V
		PIC16C5X-10E	—	4.8	10	mA	FOSC = 10 MHz, VDD = 5.5V
		PIC16C5X-HSE	—	4.8	10	mA	FOSC = 10 MHz, VDD = 5.5V
		PIC16C5X-HSE	—	9.0	20	mA	FOSC = 16 MHz, VDD = 5.5V
D020	IPD	<b>Power-down Current</b> <sup>(2)</sup>	—	5.0	22	μA	VDD = 3.25V, WDT enabled
			—	0.8	18	μA	VDD = 3.25V, WDT disabled

\* These parameters are characterized but not tested.

† Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

**Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

**2:** The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.

a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.

b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.

**3:** Does not include current through REXT. The current through the resistor can be estimated by the formula:  $I_R = VDD/2R_{EXT}$  (mA) with REXT in kΩ.

13.5 Timing Parameter Symbolology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

- 1. TppS2ppS
- 2. TppS

T	T
F Frequency	T Time

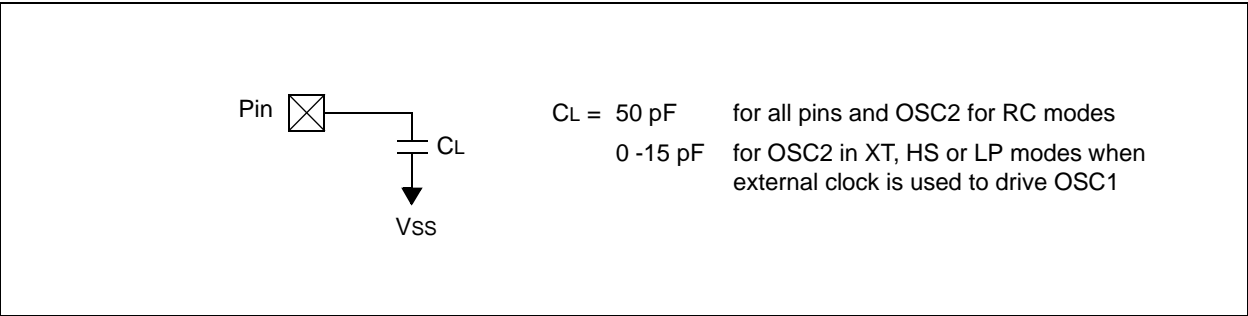
Lowercase letters (pp) and their meanings:

pp	mc MCLR
2 to	osc oscillator
ck CLKOUT	os OSC1
cy cycle time	t0 T0CKI
drt device reset timer	wdt watchdog timer
io I/O port	

Uppercase letters and their meanings:

S	P Period
F Fall	R Rise
H High	V Valid
I Invalid (Hi-impedance)	Z Hi-impedance
L Low	

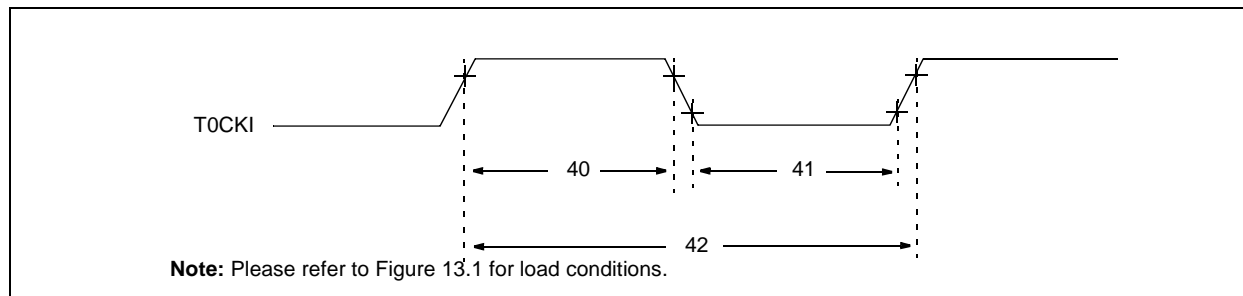
FIGURE 13-1: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16CR54A





# PIC16C5X

**FIGURE 13-5: TIMER0 CLOCK TIMINGS - PIC16CR54A**



**TABLE 13-4: TIMER0 CLOCK REQUIREMENTS - PIC16CR54A**

AC Characteristics		Standard Operating Conditions (unless otherwise specified)					
		Operating Temperature					
		0°C ≤ TA ≤ +70°C for commercial					
		-40°C ≤ TA ≤ +85°C for industrial					
		-40°C ≤ TA ≤ +125°C for extended					
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
40	Tt0H	T0CKI High Pulse Width					
		- No Prescaler	0.5 TCY + 20*	—	—	ns	
		- With Prescaler	10*	—	—	ns	
41	Tt0L	T0CKI Low Pulse Width					
		- No Prescaler	0.5 TCY + 20*	—	—	ns	
		- With Prescaler	10*	—	—	ns	
42	Tt0P	T0CKI Period	20 or $\frac{TCY + 40}{N}$ *	—	—	ns	Whichever is greater. N = Prescale Value (1, 2, 4,..., 256)

\* These parameters are characterized but not tested.

† Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 14-6: MAXIMUM IPD vs. VDD, WATCHDOG DISABLED

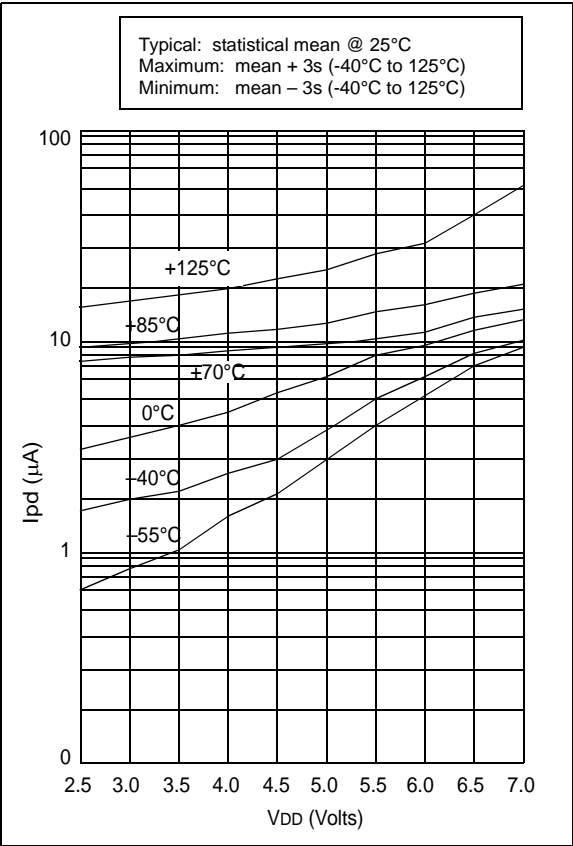


FIGURE 14-7: TYPICAL IPD vs. VDD, WATCHDOG ENABLED

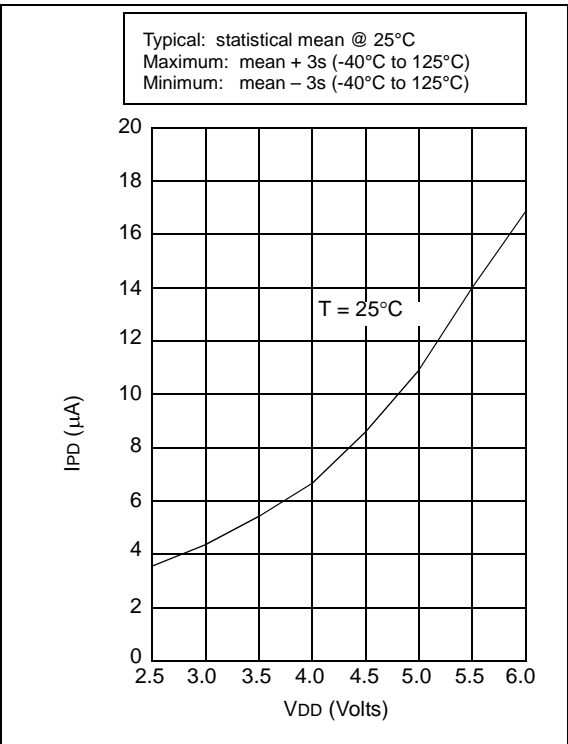
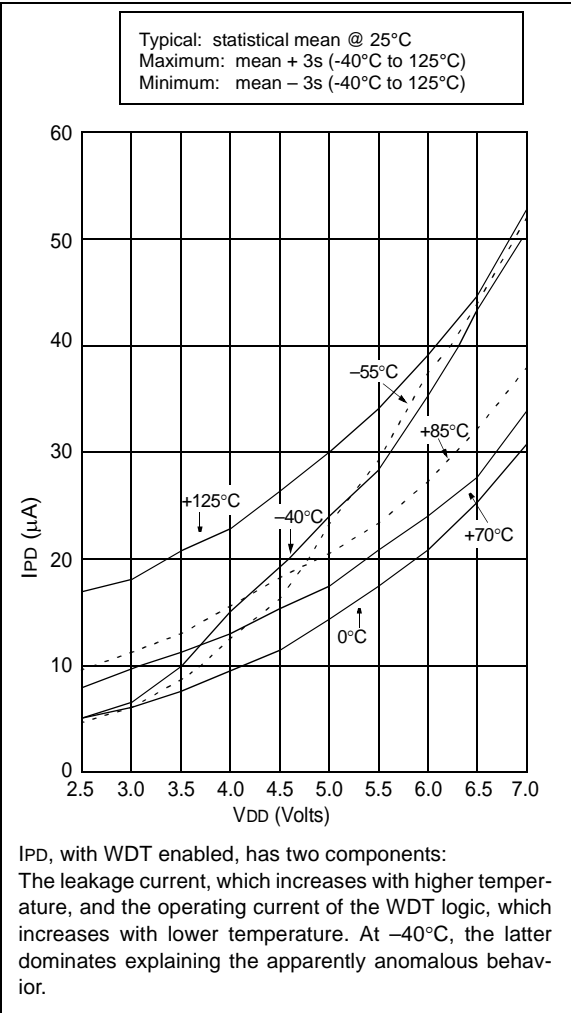


FIGURE 14-8: MAXIMUM IPD vs. VDD, WATCHDOG ENABLED



## 15.0 ELECTRICAL CHARACTERISTICS - PIC16C54A

### Absolute Maximum Ratings<sup>(†)</sup>

Ambient temperature under bias .....	–55°C to +125°C
Storage temperature .....	–65°C to +150°C
Voltage on VDD with respect to VSS .....	0 to +7.5V
Voltage on MCLR with respect to VSS.....	0 to +14V
Voltage on all other pins with respect to VSS .....	–0.6V to (VDD + 0.6V)
Total power dissipation <sup>(1)</sup> .....	800 mW
Max. current out of Vss pin .....	150 mA
Max. current into VDD pin .....	100 mA
Max. current into an input pin (T0CKI only) .....	±500 µA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0 or V <sub>I</sub> > VDD).....	±20 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > VDD) .....	±20 mA
Max. output current sunk by any I/O pin .....	25 mA
Max. output current sourced by any I/O pin .....	20 mA
Max. output current sourced by a single I/O port (PORTA or B) .....	50 mA
Max. output current sunk by a single I/O port (PORTA or B) .....	50 mA

**Note 1:** Power dissipation is calculated as follows:  $P_{dis} = V_{DD} \times \{I_{DD} - \sum I_{OH}\} + \sum \{(V_{DD} - V_{OH}) \times I_{OH}\} + \sum (V_{OL} \times I_{OL})$

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

# PIC16C5X

**TABLE 15-1: EXTERNAL CLOCK TIMING REQUIREMENTS - PIC16C54A**

<b>Standard Operating Conditions (unless otherwise specified)</b> Operating Temperature      0°C ≤ TA ≤ +70°C for commercial -40°C ≤ TA ≤ +85°C for industrial -20°C ≤ TA ≤ +85°C for industrial - PIC16LV54A-02I -40°C ≤ TA ≤ +125°C for extended							
<b>AC Characteristics</b>							
Param No.	Symbol	Characteristic	Min	Typ†	Max	Units	Conditions
1	Tosc	External CLKIN Period <sup>(1)</sup>	250	—	—	ns	XT osc mode
			500	—	—	ns	XT osc mode (PIC16LV54A)
			250	—	—	ns	HS osc mode (04)
			100	—	—	ns	HS osc mode (10)
			50	—	—	ns	HS osc mode (20)
			5.0	—	—	μs	LP osc mode
		Oscillator Period <sup>(1)</sup>	250	—	—	ns	RC osc mode
			500	—	—	ns	RC osc mode (PIC16LV54A)
			250	—	10,000	ns	XT osc mode
			500	—	—	ns	XT osc mode (PIC16LV54A)
			250	—	250	ns	HS osc mode (04)
			100	—	250	ns	HS osc mode (10)
			50	—	250	ns	HS osc mode (20)
			5.0	—	200	μs	LP osc mode
2	Tcy	Instruction Cycle Time <sup>(2)</sup>	—	4/FOSC	—	—	
3	TosL, TosH	Clock in (OSC1) Low or High Time	85*	—	—	ns	XT oscillator
			20*	—	—	ns	HS oscillator
			2.0*	—	—	μs	LP oscillator
4	TosR, TosF	Clock in (OSC1) Rise or Fall Time	—	—	25*	ns	XT oscillator
			—	—	25*	ns	HS oscillator
			—	—	50*	ns	LP oscillator

\* These parameters are characterized but not tested.

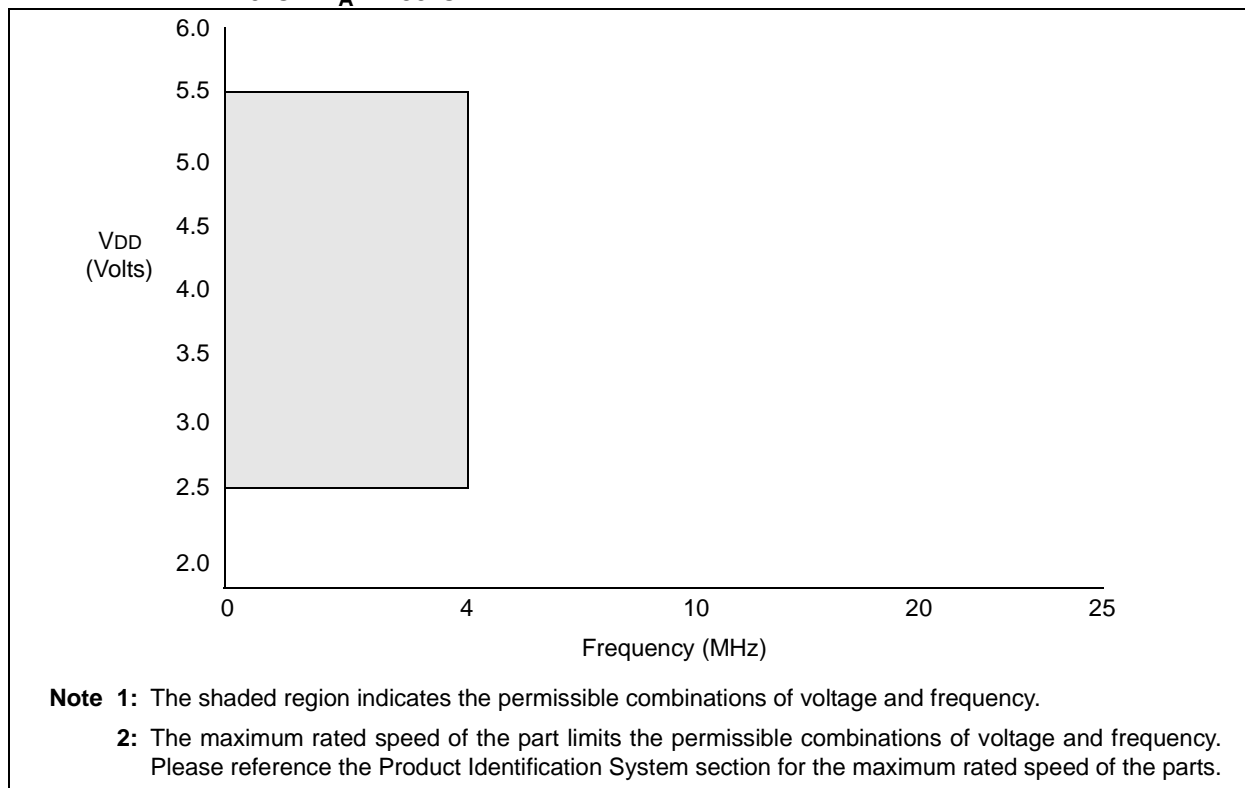
† Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

**Note 1:** All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption.

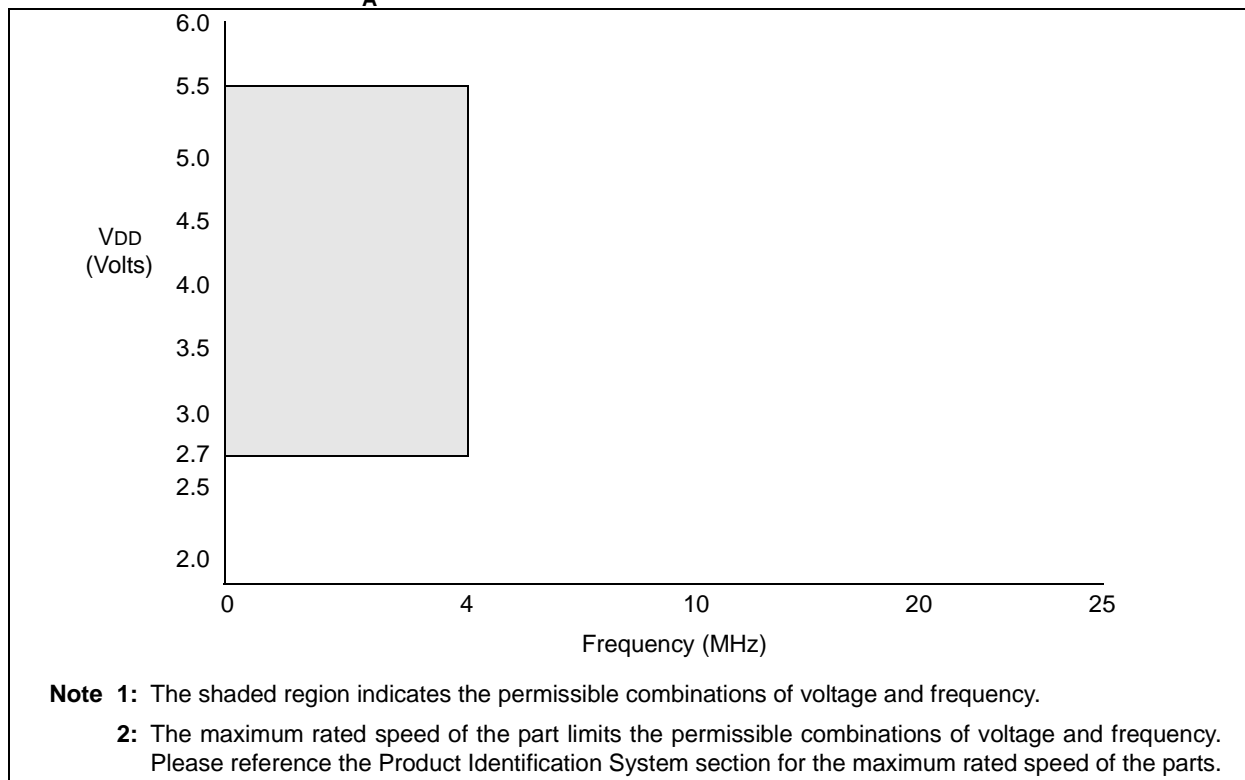
When an external clock input is used, the "max" cycle time limit is "DC" (no clock) for all devices.

**2:** Instruction cycle period (Tcy) equals four times the input oscillator time base period.

**FIGURE 17-3: PIC16LC54C/55A/56A/57C/58B VOLTAGE-FREQUENCY GRAPH,  $0^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$**



**FIGURE 17-4: PIC16LC54C/55A/56A/57C/58B VOLTAGE-FREQUENCY GRAPH,  $-40^{\circ}\text{C} \leq T_A \leq 0^{\circ}\text{C}$**



# PIC16C5X

## 17.1 DC Characteristics: PIC16C54C/C55A/C56A/C57C/C58B-04, 20 (Commercial, Industrial) PIC16LC54C/LC55A/LC56A/LC57C/LC58B-04 (Commercial, Industrial) PIC16CR54C/CR56A/CR57C/CR58B-04, 20 (Commercial, Industrial) PIC16LCR54C/LCR56A/LCR57C/LCR58B-04 (Commercial, Industrial)

<b>PIC16C5X</b> <b>PIC16LCR5X</b> (Commercial, Industrial)		<b>Standard Operating Conditions (unless otherwise specified)</b> Operating Temperature $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$ for commercial $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ for industrial					
<b>PIC16C5X</b> <b>PIC16CR5X</b> (Commercial, Industrial)		<b>Standard Operating Conditions (unless otherwise specified)</b> Operating Temperature $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$ for commercial $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ for industrial					
Param No.	Symbol	Characteristic/Device	Min	Typ†	Max	Units	Conditions
D020	IPD	<b>Power-down Current<sup>(2)</sup></b>					
		PIC16LC5X	—	0.25	2	μA	VDD = 2.5V, WDT disabled, Commercial
			—	0.25	3	μA	VDD = 2.5V, WDT disabled, Industrial
			—	1	5	μA	VDD = 2.5V, WDT enabled, Commercial
			—	1.25	8	μA	VDD = 2.5V, WDT enabled, Industrial
D020A		PIC16C5X	—	0.25	4.0	μA	VDD = 3.0V, WDT disabled, Commercial
			—	0.25	5.0	μA	VDD = 3.0V, WDT disabled, Industrial
			—	1.8	7.0*	μA	VDD = 5.5V, WDT disabled, Commercial
			—	2.0	8.0*	μA	VDD = 5.5V, WDT disabled, Industrial
			—	4	12*	μA	VDD = 3.0V, WDT enabled, Commercial
			—	4	14*	μA	VDD = 3.0V, WDT enabled, Industrial
			—	9.8	27*	μA	VDD = 5.5V, WDT enabled, Commercial
			—	12	30*	μA	VDD = 5.5V, WDT enabled, Industrial

Legend: Rows with standard voltage device data only are shaded for improved readability.

\* These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C, unless otherwise stated. These parameters are for design guidance only, and are not tested.

- Note 1:** This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
- Note 2:** The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
- a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to VSS, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
- b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
- Note 3:** Does not include current through REXT. The current through the resistor can be estimated by the formula:  
 $I_R = V_{DD}/2R_{EXT}$  (mA) with REXT in kΩ.

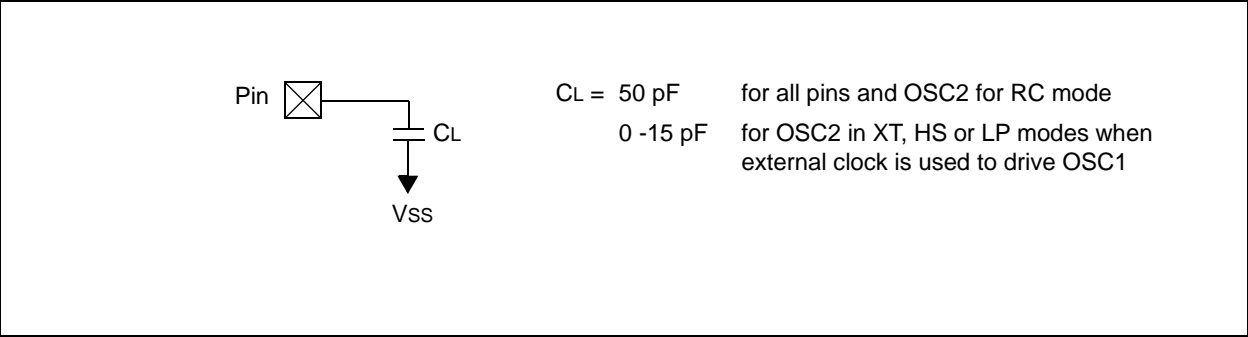
17.4 Timing Parameter Symbolology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

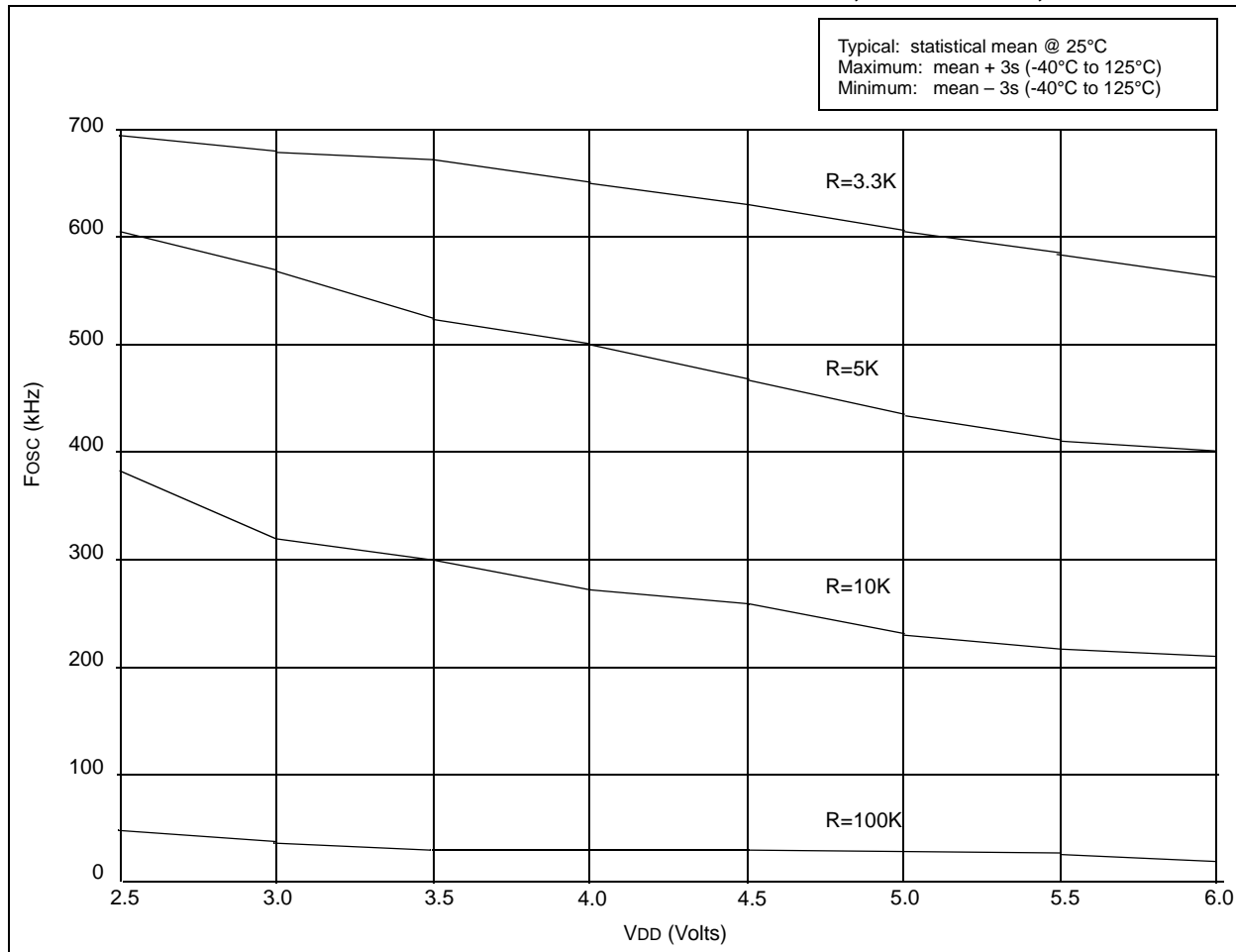
- 1. TppS2ppS
- 2. TppS

T		T	Time
F	Frequency		
Lowercase letters (pp) and their meanings:			
pp		mc	MCLR
2	to	osc	oscillator
ck	CLKOUT	os	OSC1
cy	cycle time	t0	T0CKI
drt	device reset timer	wdt	watchdog timer
io	I/O port		
Uppercase letters and their meanings:			
S		P	Period
F	Fall	R	Rise
H	High	V	Valid
I	Invalid (Hi-impedance)	Z	Hi-impedance
L	Low		

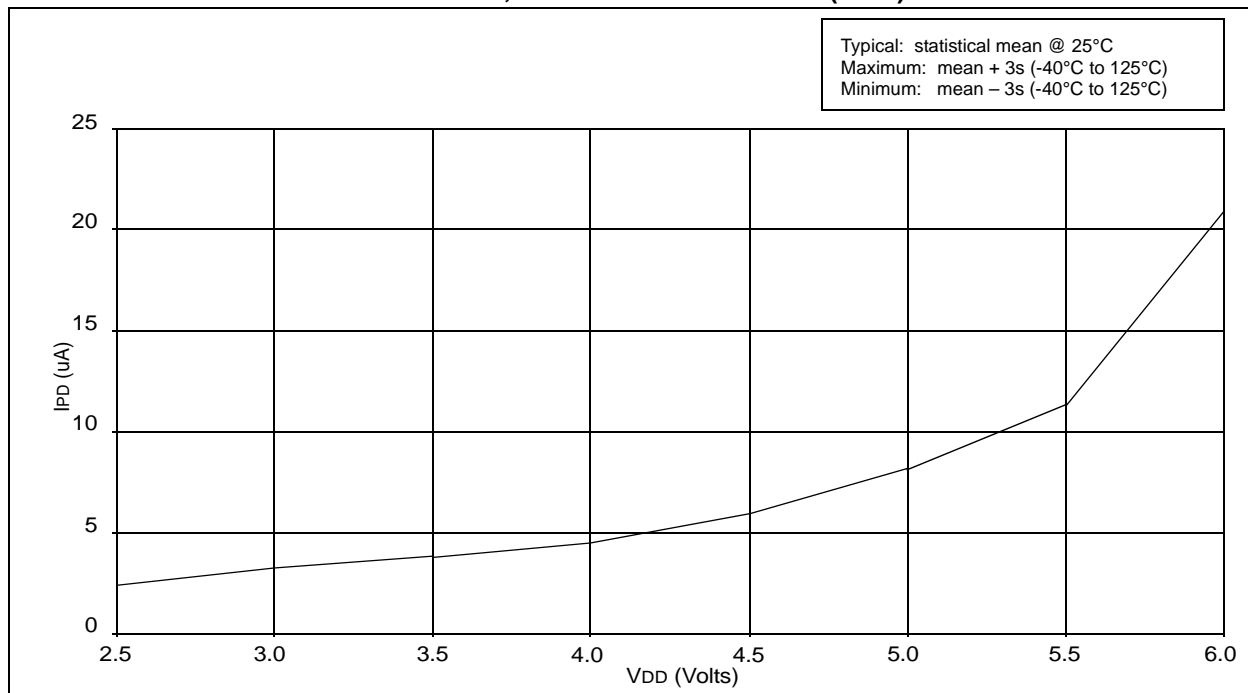
FIGURE 17-5: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54C/CR54C/C55A/C56A/CR56A/C57C/CR57C/C58B/CR58B-04, 20



**FIGURE 18-4: TYPICAL RC OSCILLATOR FREQUENCY vs.  $V_{DD}$ ,  $C_{EXT} = 300$  pF,  $25^{\circ}\text{C}$**



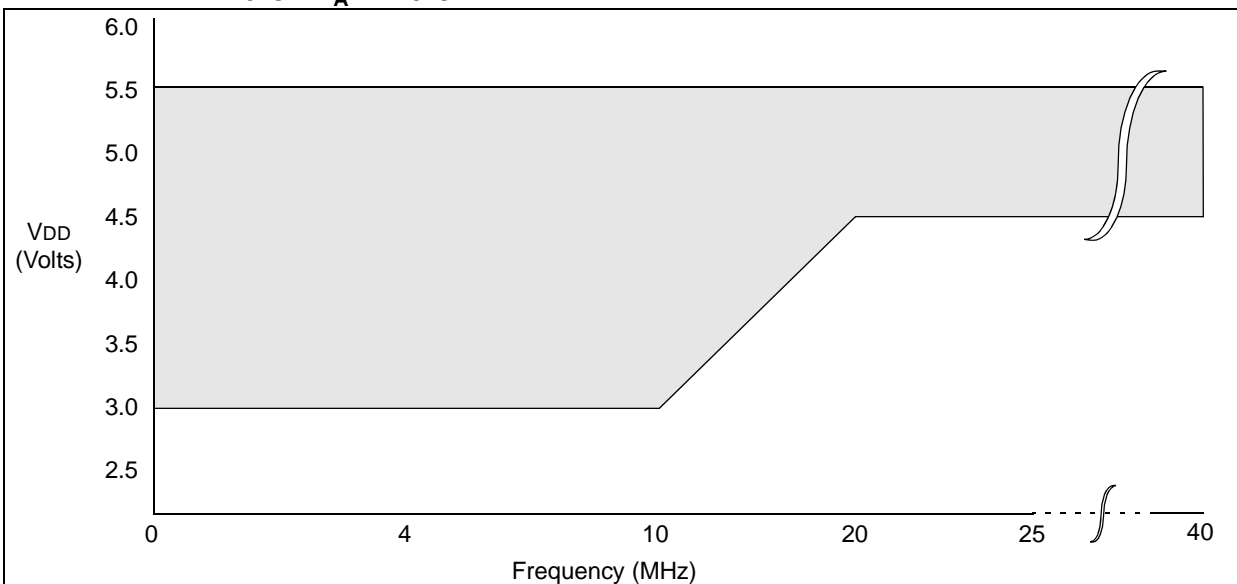
**FIGURE 18-5: TYPICAL  $I_{PD}$  vs.  $V_{DD}$ , WATCHDOG DISABLED ( $25^{\circ}\text{C}$ )**





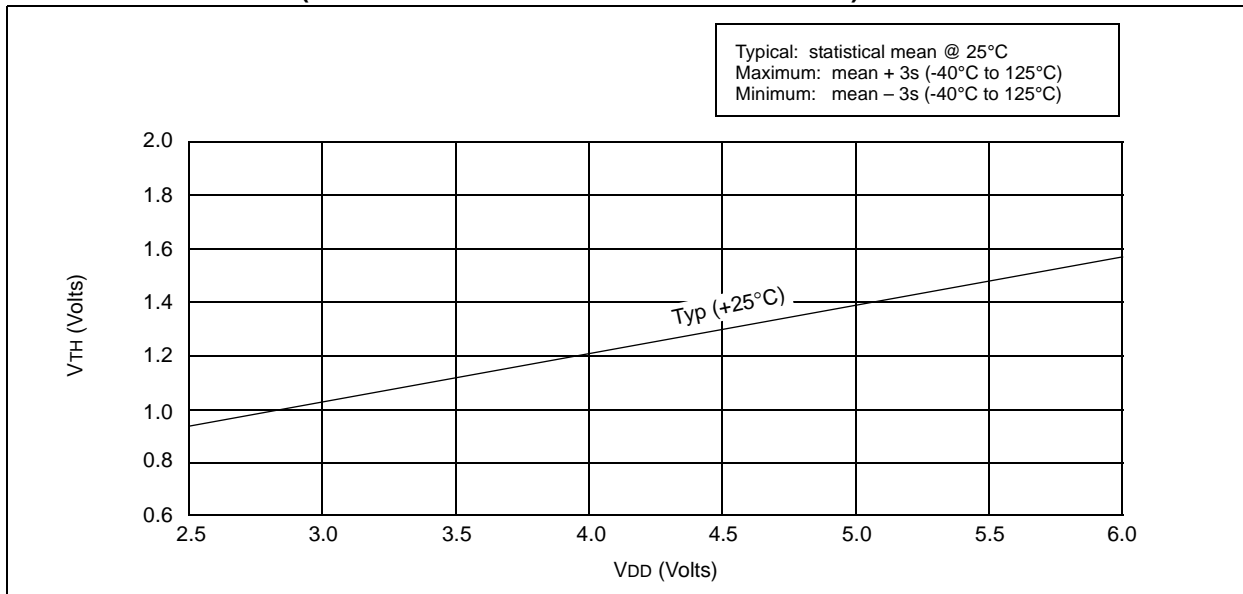
# PIC16C5X

**FIGURE 19-1: PIC16C54C/C55A/C56A/C57C/C58B-40 VOLTAGE-FREQUENCY GRAPH,  $0^{\circ}\text{C} \leq T_A \leq +70^{\circ}\text{C}$**

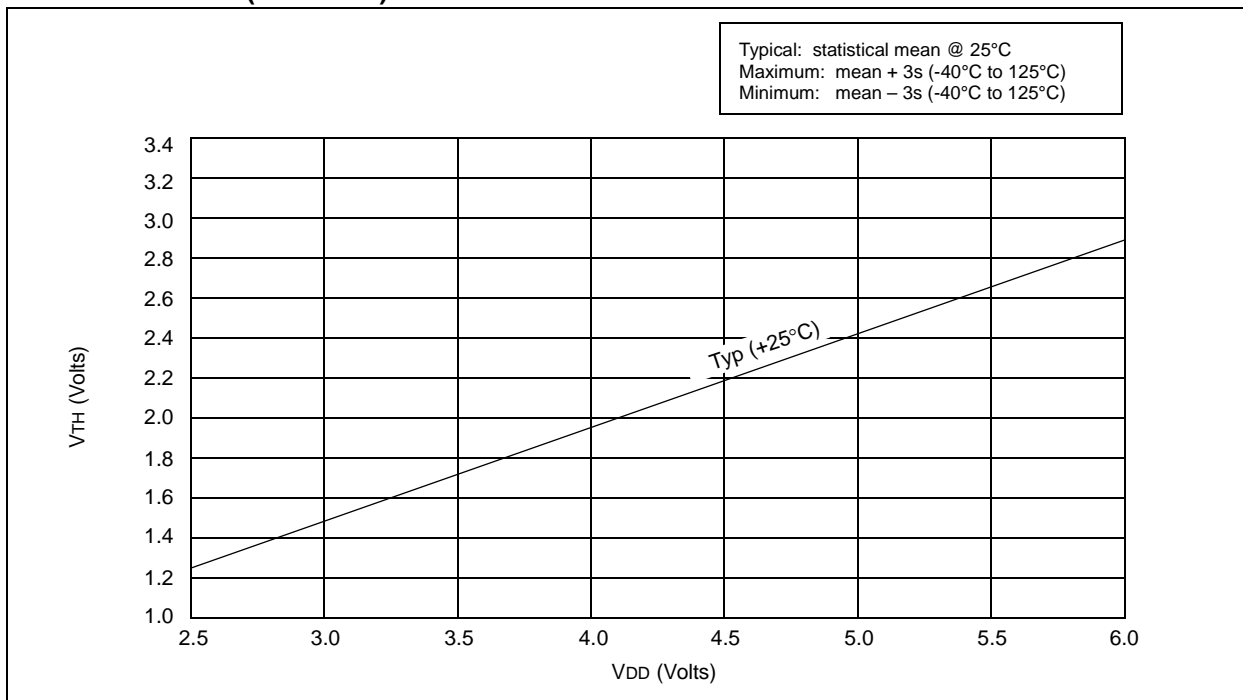


- Note 1:** The shaded region indicates the permissible combinations of voltage and frequency.
- Note 2:** The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.
- Note 3:** Operation between 20 to 40 MHz requires the following:
- VDD between 4.5V. and 5.5V
  - OSC1 externally driven
  - OSC2 not connected
  - HS mode
  - Commercial temperatures
- Devices qualified for 40 MHz operation have -40 designation (ex: PIC16C54C-40/P).
- Note 4:** For operation between DC and 20 MHz, see Section 17.1.

**FIGURE 20-4:  $V_{TH}$  (INPUT THRESHOLD TRIP POINT VOLTAGE) OF I/O PINS vs.  $V_{DD}$**



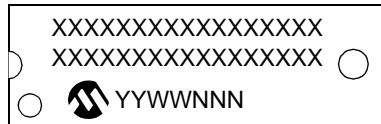
**FIGURE 20-5:  $V_{TH}$  (INPUT THRESHOLD TRIP POINT VOLTAGE) OF OSC1 INPUT (HS MODE) vs.  $V_{DD}$**



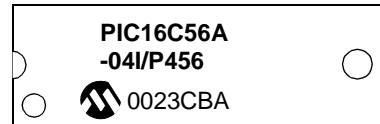
## 21.0 PACKAGING INFORMATION

### 21.1 Package Marketing Information

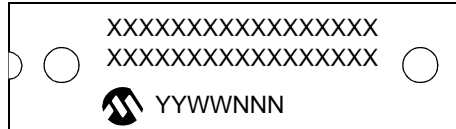
#### 18-Lead PDIP



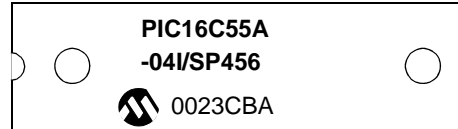
#### Example



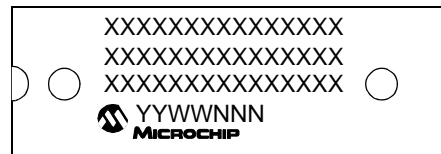
#### 28-Lead Skinny PDIP (.300")



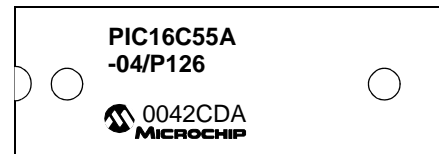
#### Example



#### 28-Lead PDIP (.600")



#### Example



#### 18-Lead SOIC



#### Example



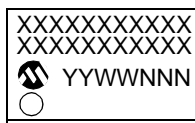
#### 28-Lead SOIC



#### Example



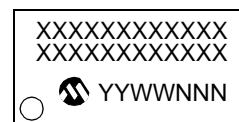
#### 20-Lead SSOP



#### Example



#### 28-Lead SSOP

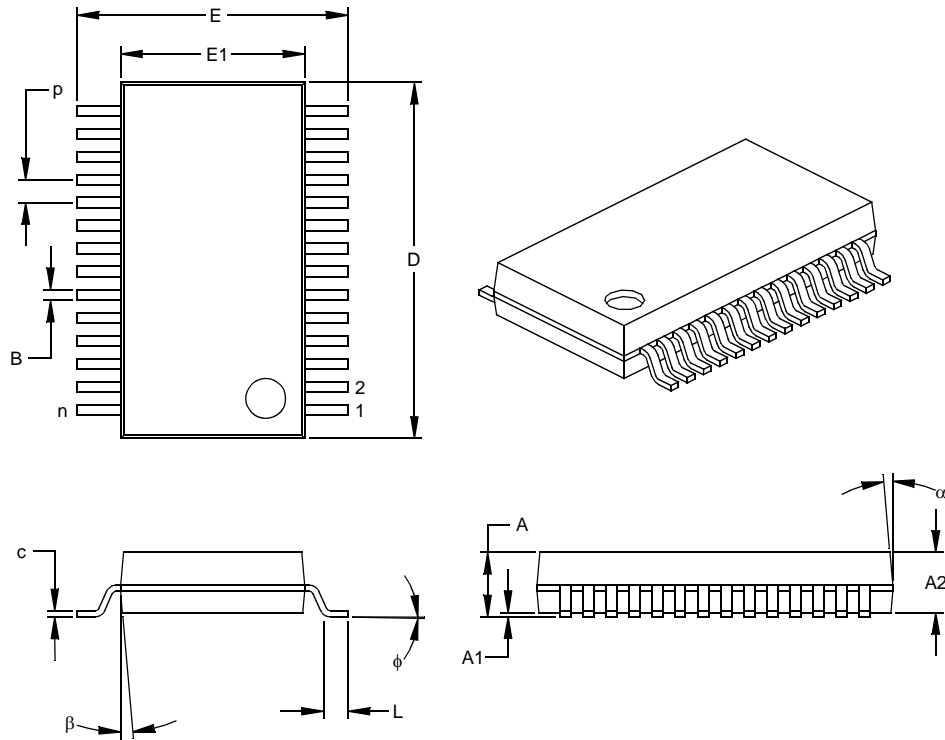


#### Example



## 28-Lead Plastic Shrink Small Outline (SS) – 209 mil, 5.30 mm (SSOP)

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		INCHES			MILLIMETERS*		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		28			28	
Pitch	P		.026			0.65	
Overall Height	A	.068	.073	.078	1.73	1.85	1.98
Molded Package Thickness	A2	.064	.068	.072	1.63	1.73	1.83
Standoff §	A1	.002	.006	.010	0.05	0.15	0.25
Overall Width	E	.299	.309	.319	7.59	7.85	8.10
Molded Package Width	E1	.201	.207	.212	5.11	5.25	5.38
Overall Length	D	.396	.402	.407	10.06	10.20	10.34
Foot Length	L	.022	.030	.037	0.56	0.75	0.94
Lead Thickness	c	.004	.007	.010	0.10	0.18	0.25
Foot Angle	φ	0	4	8	0.00	101.60	203.20
Lead Width	B	.010	.013	.015	0.25	0.32	0.38
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

\* Controlling Parameter  
§ Significant Characteristic

**Notes:**

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-150

Drawing No. C04-073

## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	-	XX	X	/XX	XXX
Device		Frequency Range/OSC Type	Temperature Range	Package	Pattern
Device		PIC16C54 PIC16C54A PIC16CR54A PIC16C54C PIC16CR54C PIC16C55 PIC16C55A PIC16C56 PIC16C56A PIC16CR56A PIC16C57 PIC16C57C PIC16CR57C PIC16C58B PIC16CR58B	PIC16C54T <sup>(2)</sup> PIC16C54AT <sup>(2)</sup> PIC16CR54AT <sup>(2)</sup> PIC16C54CT <sup>(2)</sup> PIC16CR54CT <sup>(2)</sup> PIC16C55T <sup>(2)</sup> PIC16C55AT <sup>(2)</sup> PIC16C56T <sup>(2)</sup> PIC16C56AT <sup>(2)</sup> PIC16CR56AT <sup>(2)</sup> PIC16C57T <sup>(2)</sup> PIC16C57CT <sup>(2)</sup> PIC16CR57CT <sup>(2)</sup> PIC16C58BT <sup>(2)</sup> PIC16CR58BT <sup>(2)</sup>		
Frequency Range/ Oscillator Type		RC Resistor Capacitor LP Low Power Crystal XT Standard Crystal/Resonator HS High Speed Crystal 02 200 KHz (LP) or 2 MHz (XT and RC) 04 200 KHz (LP) or 4 MHz (XT and RC) 10 10 MHz (HS only) 20 20 MHz (HS only) 40 40 MHz (HS only) b <sup>(4)</sup> No oscillator type for JW packages <sup>(3)</sup>			
		*RC/LP/XT/HS are for 16C54/55/56/57 devices only -02 is available for 16LV54A only -04/10/20 options are available for all other devices -40 is available for 16C54C/55A/56A/57C/58B devices only			
Temperature Range		b <sup>(4)</sup> = 0°C to +70°C I = -40°C to +85°C E = -40°C to +125°C			
Package		S = Die in Waffle Pack JW = 28-pin 600 mil/18-pin 300 mil windowed CER-DIP <sup>(3)</sup> P = 28-pin 600 mil/18-pin 300 mil PDIP SO = 300 mil SOIC SS = 209 mil SSOP SP = 28-pin 300 mil Skinny PDIP			
		*See Section 21 for additional package information.			
Pattern		QTP, SQTP, ROM code (factory specified) or Special Requirements. Blank for OTP and Windowed devices.			

### Examples:

- PIC16C55A - 04/P 301 = Commercial Temp., PDIP package, 4 MHz, standard VDD limits, QTP pattern #301
- PIC16LC54C - 04I/SO Industrial Temp., SOIC package, 200 kHz, extended VDD limits
- PIC16C57 - RC/SP = RC Oscillator, commercial temp, skinny PDIP package, 4 MHz, standard VDD limits
- PIC16C58BT -40/SS 123 = commercial temp, SSOP package in tape and reel, 4 MHz, extended VDD limits, ROM pattern #123

- Note**
- 1: C = normal voltage range  
LC = extended
  - 2: T = in tape and reel - SOIC and SSOP packages only
  - 3: JW Devices are UV erasable and can be programmed to any device configuration. JW Devices meet the electrical requirements of each oscillator type, including LC devices.
  - 4: b = Blank

## Sales and Support

### Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

1. Your local Microchip sales office
2. The Microchip Worldwide Site ([www.microchip.com](http://www.microchip.com))